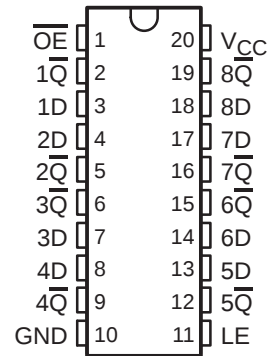


SN54ABT533, SN74ABT533 OCTAL TRANSPARENT D-TYPE LATCHES WITH 3-STATE OUTPUTS

SCBS186A – FEBRUARY 1991 – REVISED JULY 1994

- State-of-the-Art *EPIC-II B*™ BiCMOS Design Significantly Reduces Power Dissipation
- Latch-Up Performance Exceeds 500 mA Per JEDEC Standard JESD-17
- Typical V_{OLP} (Output Ground Bounce) < 1 V at $V_{CC} = 5$ V, $T_A = 25^\circ\text{C}$
- High-Drive Outputs ($-32\text{-mA } I_{OH}$, $64\text{-mA } I_{OL}$)
- Package Options Include Plastic Small-Outline (DW) and Shrink Small-Outline (DB) Packages, Ceramic Chip Carriers (FK), and Plastic (N) and Ceramic (J) DIPs

SN54ABT533 . . . J PACKAGE
SN74ABT533 . . . DB, DW, OR N PACKAGE
(TOP VIEW)



description

The 'ABT533 are 8-bit transparent D-type latches with 3-state outputs designed specifically for driving highly capacitive or relatively low-impedance loads. They are particularly suitable for implementing buffer registers, I/O ports, bidirectional bus drivers, and working registers.

When the latch-enable (LE) input is high, the $\overline{Q}$ outputs follow the complements of the data (D) inputs. When LE is taken low, the $\overline{Q}$ outputs are latched at the inverse of the levels set up at the D inputs. The 'ABT533 provides inverted data at its outputs.

A buffered output-enable ($\overline{OE}$) input can be used to place the eight outputs in either a normal logic state (high or low logic levels) or a high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and the increased drive provide the capability to drive bus lines without need for interface or pullup components.

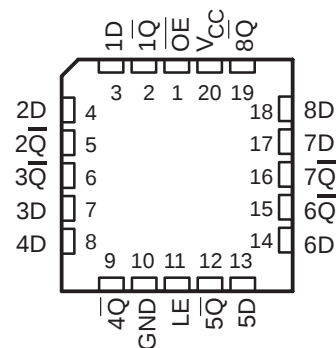
$\overline{OE}$ does not affect the internal operations of the latches. Previously stored data can be retained or new data can be entered while the outputs are in the high-impedance state.

To ensure the high-impedance state during power up or power down, $\overline{OE}$ should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

The SN74ABT533 is available in TI's shrink small-outline package (DB), which provides the same I/O pin count and functionality of standard small-outline packages in less than half the printed-circuit-board area.

The SN54ABT533 is characterized for operation over the full military temperature range of -55°C to 125°C . The SN74ABT533 is characterized for operation from -40°C to 85°C .

SN54ABT533 . . . FK PACKAGE
(TOP VIEW)



EPIC-II B is a trademark of Texas Instruments Incorporated.

UNLESS OTHERWISE NOTED this document contains PRODUCTION DATA information current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

**TEXAS
INSTRUMENTS**

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SN54ABT533, SN74ABT533

OCTAL TRANSPARENT D-TYPE LATCHES

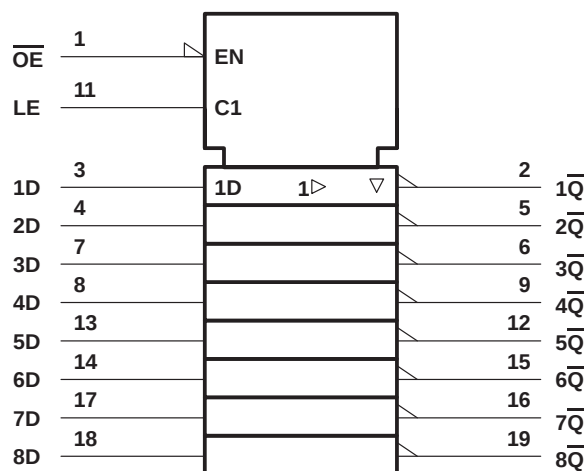
WITH 3-STATE OUTPUTS

SCBS186A – FEBRUARY 1991 – REVISED JULY 1994

FUNCTION TABLE
(each latch)

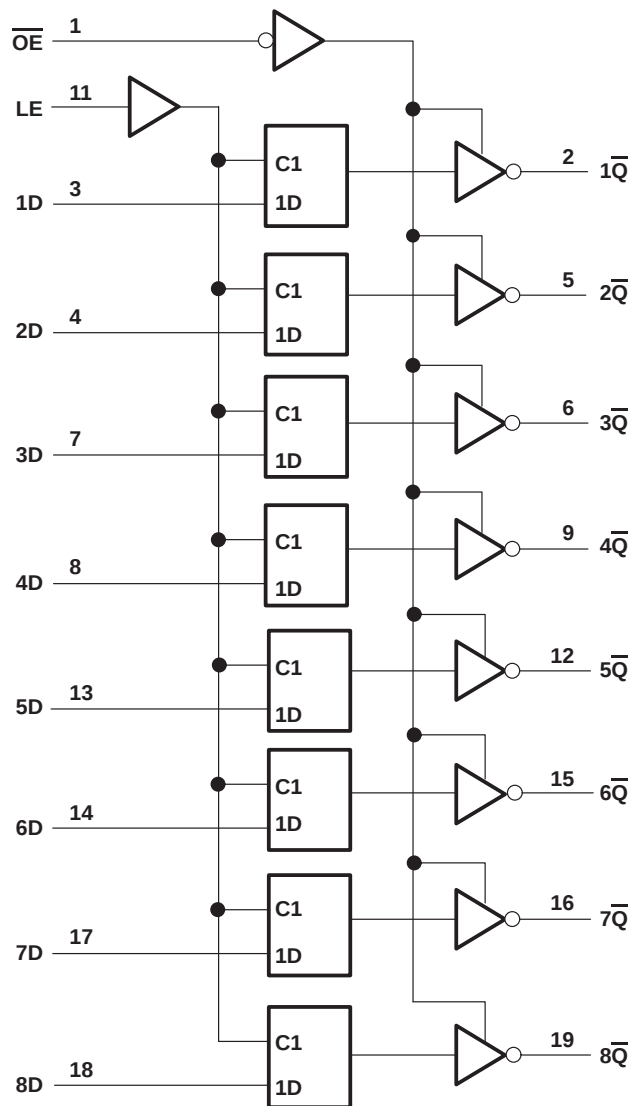
INPUTS			OUTPUT $\overline{Q}$
$\overline{OE}$	LE	D	
L	H	H	L
L	H	L	H
L	L	X	$\overline{Q_0}$
H	X	X	Z

logic symbol[†]



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)



SN54ABT533, SN74ABT533 OCTAL TRANSPARENT D-TYPE LATCHES WITH 3-STATE OUTPUTS

SCBS186A – FEBRUARY 1991 – REVISED JULY 1994

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage range, V_{CC}	–0.5 V to 7 V
Input voltage range, V_I (see Note 1)	–0.5 V to 7 V
Voltage range applied to any output in the high state or power-off state, V_O	–0.5 V to 5.5 V
Current into any output in the low state, I_O : SN54ABT533	96 mA
SN74ABT533	128 mA
Input clamp current, I_{IK} ($V_I < 0$)	–18 mA
Output clamp current, I_{OK} ($V_O < 0$)	–50 mA
Maximum power dissipation at $T_A = 55^\circ\text{C}$ (in still air) (see Note 2): DB package	0.6 W
DW package	1.6 W
N package	1.3 W
Storage temperature range	–65°C to 150°C

[†] Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
2. The maximum package power dissipation is calculated using a junction temperature of 150°C and a board trace length of 750 mils, except for the N package, which has a trace length of zero. For more information, refer to the *Package Thermal Considerations* application note in the 1994 *ABT Advanced BiCMOS Technology Data Book*, literature number SCBD002B.

recommended operating conditions (see Note 3)

		SN54ABT533		SN74ABT533		UNIT
		MIN	MAX	MIN	MAX	
V_{CC}	Supply voltage	4.5	5.5	4.5	5.5	V
V_{IH}	High-level input voltage	2		2		V
V_{IL}	Low-level input voltage		0.8		0.8	V
V_I	Input voltage	0	V_{CC}	0	V_{CC}	V
I_{OH}	High-level output current		–24		–32	mA
I_{OL}	Low-level output current		48		64	mA
$\Delta t / \Delta v$	Input transition rise or fall rate		10		10	ns/V
T_A	Operating free-air temperature	–55	125	–40	85	°C

NOTE 3: Unused or floating inputs must be held high or low.

SN54ABT533, SN74ABT533

OCTAL TRANSPARENT D-TYPE LATCHES

WITH 3-STATE OUTPUTS

SCBS186A – FEBRUARY 1991 – REVISED JULY 1994

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS		T _A = 25°C			SN54ABT533		SN74ABT533		UNIT
			MIN	TYP [†]	MAX	MIN	MAX	MIN	MAX	
V _{IK}	V _{CC} = 4.5 V, I _I = -18 mA		-1.2			-1.2		-1.2		V
V _{OH}	V _{CC} = 4.5 V,	I _{OH} = -3 mA	2.5			2.5		2.5		V
	V _{CC} = 5 V,	I _{OH} = -3 mA	3			3		3		
	V _{CC} = 4.5 V	I _{OH} = -24 mA	2			2				
		I _{OH} = -32 mA	2*					2		
V _{OL}	V _{CC} = 4.5 V	I _{OL} = 48 mA	0.55			0.55				V
		I _{OL} = 64 mA	0.55*					0.55		
I _I	V _{CC} = 5.5 V, V _I = V _{CC} or GND		±1			±1		±1		μA
I _{OZH}	V _{CC} = 5.5 V, V _O = 2.7 V		10 [‡]			10 [‡]		10 [‡]		μA
I _{OZL}	V _{CC} = 5.5 V, V _O = 0.5 V		-10 [‡]			-10 [‡]		-10 [‡]		μA
I _{off}	V _{CC} = 0, V _I or V _O ≤ 4.5 V		±150					±150		μA
I _{CEX}	V _{CC} = 5.5 V, V _O = 5.5 V	Outputs high	50			50		50		μA
I _O [§]	V _{CC} = 5.5 V, V _O = 2.5 V		-50	-140	-180	-50	-180	-50	-180	mA
I _{CC}	V _{CC} = 5.5 V, I _O = 0, V _I = V _{CC} or GND		Outputs high		1	250	250		250	μA
			Outputs low		24	30	30		30	mA
			Outputs disabled		0.5	250	250		250	μA
ΔI _{CC} [¶]	V _{CC} = 5.5 V, One input at 3.4 V, Other inputs at V _{CC} or GND		Outputs enabled		1.5		1.5		1.5	mA
			Outputs disabled		1.5		1.5		1.5	
			Control inputs		1.5		1.5		1.5	
C _i	V _I = 2.5 V or 0.5 V		3							pF
C _O	V _O = 2.5 V or 0.5 V		9							pF

* On products compliant to MIL-STD-883, Class B, this parameter does not apply.

† All typical values are at V_{CC} = 5 V.

‡ This data sheet limit may vary among suppliers.

§ Not more than one output should be tested at a time, and the duration of the test should not exceed one second.

¶ This is the increase in supply current for each input that is at the specified TTL voltage level rather than V_{CC} or GND.

timing requirements over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure1)

		V _{CC} = 5 V, T _A = 25°C		SN54ABT533		SN74ABT533		UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	
t _w	Pulse duration, LE high	3.3		3.3		3.3		ns
t _{su}	Setup time, data before LE↓		High or low	2.1		2.1		ns
t _h	Hold time, data after LE↓		High or low	1.5 [§]		1.5 [§]		ns

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SN54ABT533, SN74ABT533
OCTAL TRANSPARENT D-TYPE LATCHES
WITH 3-STATE OUTPUTS

SCBS186A – FEBRUARY 1991 – REVISED JULY 1994

switching characteristics over recommended ranges of supply voltage and operating free-air temperature, $C_L = 50$ pF (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	$V_{CC} = 5$ V, $T_A = 25^\circ\text{C}$			SN54ABT533		SN74ABT533		UNIT
			MIN	TYP	MAX	MIN	MAX	MIN	MAX	
t_{PLH}	D	$\bar{Q}$	1.9	4.2	5.4	1.9	6.7	1.9	6.4	ns
t_{PHL}			3.1	4.9	6.3	3.1	6.9	3.1	6.6	
t_{PLH}	LE	$\bar{Q}$	2.7	4.9	6.2	2.7	7.6	2.7	7.3	ns
t_{PHL}			3.5	5.4	6.8	3.5	7.5	3.5	7.3	
t_{PZH}	$\overline{OE}$	$\bar{Q}$	1.6	3.7	4.8	1.6	5.8	1.6	5.7	ns
t_{PZL}			2.4	4.2	6.2	2.4	6.9	2.4	6.7	
t_{PHZ}	$\overline{OE}$	$\bar{Q}$	2.8	5.1	6.2	2.8	7.2	2.8	6.9	ns
t_{PLZ}			2	4.1	6	2	6.9	2	6.5	

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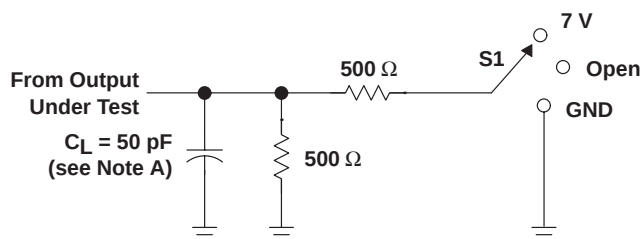
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OCTAL TRANSPARENT D-TYPE LATCHES

WITH 3-STATE OUTPUTS

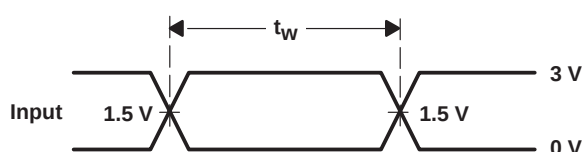
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PARAMETER MEASUREMENT INFORMATION

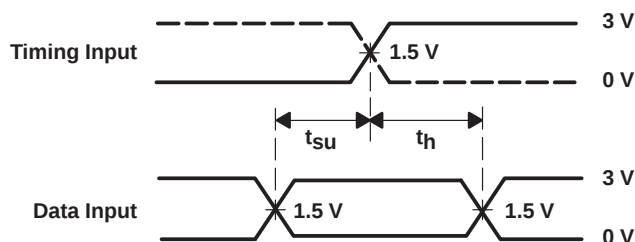


LOAD CIRCUIT FOR OUTPUTS

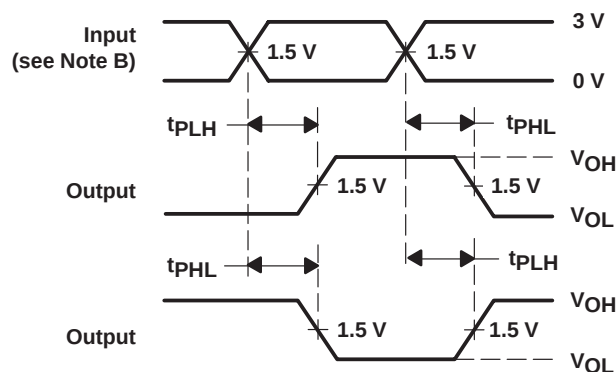
TEST	S1
t_{PLH}/t_{PHL}	Open
t_{PLZ}/t_{PZL}	7 V
t_{PHZ}/t_{PZH}	Open



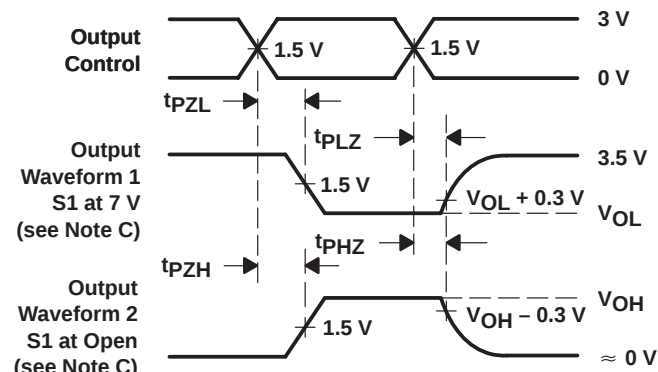
VOLTAGE WAVEFORMS
PULSE DURATION



VOLTAGE WAVEFORMS
SETUP AND HOLD TIMES



VOLTAGE WAVEFORMS
PROPAGATION DELAY TIMES
INVERTING AND NONINVERTING OUTPUTS



VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES
LOW- AND HIGH-LEVEL ENABLING

- NOTES: A. C_L includes probe and jig capacitance.
 B. All input pulses are supplied by generators having the following characteristics: $PRR \leq 10$ MHz, $Z_O = 50 \Omega$, $t_r \leq 2.5$ ns, $t_f \leq 2.5$ ns.
 C. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 D. The outputs are measured one at a time with one transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms

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